

09/701884

INFORMATION DISCLOSURE CITATION

ATTY. DOCKET NO.

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APPLICANT

(Use several sheets if necessary)

JEFFERSON et al.

FILING DATE

GROUP

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U.S. PATENT OFFICE

U.S. PATENT DOCUMENTS

***EXAMINER**

FOREIGN PATENT DOCUMENTS

TRANSLATION

OTHER DOCUMENTS (including Author, Title, Date, Pertinent pages, etc.)

WANG X-L et al: "FLAW RATE MODULATION EPITAXY OF ALGAAS/GAAS QUANTUM WIRES ON NONPLANAR SUBSTRATE" APPLIED PHYSICS LETTERS, vol. 66, no. 12, (03/1995) pp. 1506-1508

*Examiner

Kevin Quigley

Date Considered

8/19/02

Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to application.

Form PTO-FB-A820 (Also PTO-1449)